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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/763,137 01/21/2004		Ken Nakahara	88519.0002 6402		
26021	7590 11/30/2005		EXAMINER		
HOGAN & HARTSON L.L.P.			SOWARD, IDA M		
500 S. GRAN	D AVENUE				
SUITE 1900			ART UNIT	PAPER NUMBER	
LOS ANGELI	ES, CA 90071-2611		2822		

DATE MAILED: 11/30/2005

Please find below and/or attached an Office communication concerning this application or proceeding.

		A	pplication No.	Applicant(s)					
Office Action Summary		10	0/763,137	NAKAHARA, KEN	(An)				
		E	caminer	Art Unit					
		ld	a M. Soward	2822					
	The MAILING DATE of this communication appears on the cover sheet with the correspondence address Period for Reply								
A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) OR THIRTY (30) DAYS, WHICHEVER IS LONGER, FROM THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication. - If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication. - Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).									
Status									
1)⊠	Responsive to communication(s) file	ed on .							
•	•		tion is non-final.						
·—	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is								
,—	closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.								
Disposition of Claims									
4)⊠	Claim(s) 1-12 is/are pending in the a	application.							
-	4a) Of the above claim(s) is/are withdrawn from consideration.								
	☐ Claim(s) 1-6 is/are allowed.								
'	Claim(s) 7.9 and 11 is/are rejected.								
·	Claim(s) 8,10 and 12 is/are objected to.								
8)	Claim(s) are subject to restriction and/or election requirement.								
Applicati	ion Papers								
9)□	The specification is objected to by th	e Examiner.							
•	· · · · · · · · · · · · · · · · · · ·		ed or b) objected	to by the Examiner.					
10) The drawing(s) filed on is/are: a) accepted or b) objected to by the Examiner. Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).									
	Replacement drawing sheet(s) including				.121(d).				
11) The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.									
Priority ι	under 35 U.S.C. § 119								
 12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) All b) Some * c) None of: 1. Certified copies of the priority documents have been received. 2. Certified copies of the priority documents have been received in Application No. 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received. 									
2) Notice 3) Information	et(s) De of References Cited (PTO-892) De of Draftsperson's Patent Drawing Review (Function Disclosure Statement(s) (PTO-1449 or Transcript of the Park (S) (PTO-1449) Description Disclosure Statement(s) (PTO-1449)		Paper N	w Summary (PTO-413) No(s)/Mail Date of Informal Patent Application (PTO-152	2)				

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DETAILED ACTION

This Office Action is in response to the Applicant's amendment filed September 16, 2005.

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 7, 9 and 11 are rejected under 35 U.S.C. 103(a) as being unpatentable over Kadota (US 20020126719 A1) in view of Sakai (US 2003/0209723 A1).

In regard to claim 7, Kadota teaches a semiconductor light emitting device comprising a light emission layer, consisting of an GaN system semiconductor 45, 46 & 47, which is interposed between an n type GaN system semiconductor layer 44 and a p type GaN system semiconductor layer 48, wherein there is provided a B-doped ZnO electrode film when z=0 in Mg_zZn_{1-z}O (0≤z<1) (Figure 5, pages 2-3, paragraphs [0035]-[0038]).

In regard to claim 9, Kadota teaches a metal electrode 49, which supplies an electric current to the n type GaN system semiconductor layer, wherein said B-doped ZnO electrode film (when z=0 in $Mg_zZn_{1-z}O$ (0 \leq z<1)) is formed between the n type GaN system semiconductor layer 44, and the metal electrode 49.

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In regard to claim 11, Kadota teaches a metal electrode 49, which supplies an electric current to the n type GaN system semiconductor layer 44, wherein the metal electrode 49 and the B-doped ZnO electrode film (when z=0 in Mg_zZn_{1-z}O (0≤z<1)) adjoin each other and the metal electrode 49 and the B-doped ZnO electrode film are arranged so as to be contiguous to the face of the n type GaN system semiconductor layer 44 (Figure 5, pages 2-3, paragraphs [0035]-[0038]).

However, Kadota fails to teach a Mg_zZn_{1-z}O (0≤z<1) electrode film disposed on one of a GaN system semiconductor layers.

Sakai teaches a ZnO (when z=0) electrode film 21 disposed on one of a GaN system semiconductor layers 18, 16, 14 & 12 (Figure 1, page 2, paragraphs [0017]-[0025]).

Therefore it would have been obvious to one having ordinary skill in the art at the time the invention was made to modify the semiconductor light emitting device structure as taught by Kadota with the light emitting device having a ZnO (when z=0) electrode film disposed on one of a GaN system semiconductor layers to improve the light emission efficiency in a GaN-based compound semiconductor device (page 1, paragraph [0009]).

Allowable Subject Matter

Claims 1-6 are allowed.

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Claims 8, 10 and 12 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

Response to Arguments

Applicant's arguments with respect to claims 7, 9 and 11 have been considered but are most in view of the new ground(s) of rejection.

Conclusion

The prior art made of record and not relied upon is considered pertinent to applicant's disclosure.

The following patents are cited to further show the state of the art with respect to semiconductor light emitting devices:

Hori et al. (US 6,693,302 B2)

Rennie et al. (5,889,295).

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Ida M. Soward whose telephone number is 571-272-1845. The examiner can normally be reached on Monday - Thursday 6:30am to 5:00pm.

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If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Zandra V. Smith can be reached on 571-272-2429. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

IMS

November 28, 2005

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